

2SK435

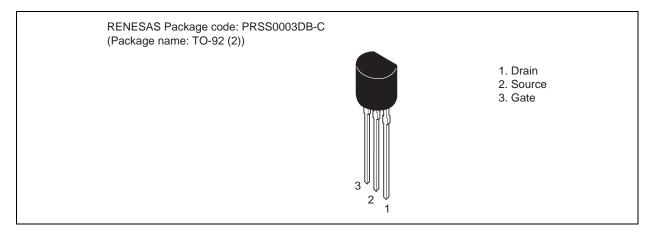
Silicon N-Channel Junction FET

REJ03G0812-0200 (Previous ADE-208-1171) Rev.2.00 Aug.10.2005

Application

Low frequency / High frequency amplifier

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DS}	22	V
Gate to source voltage	V_{GSO}	-22	V
Drain current	I _D	100	mA
Gate current	I _G	10	mA
Channel power dissipation	Pch	300	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

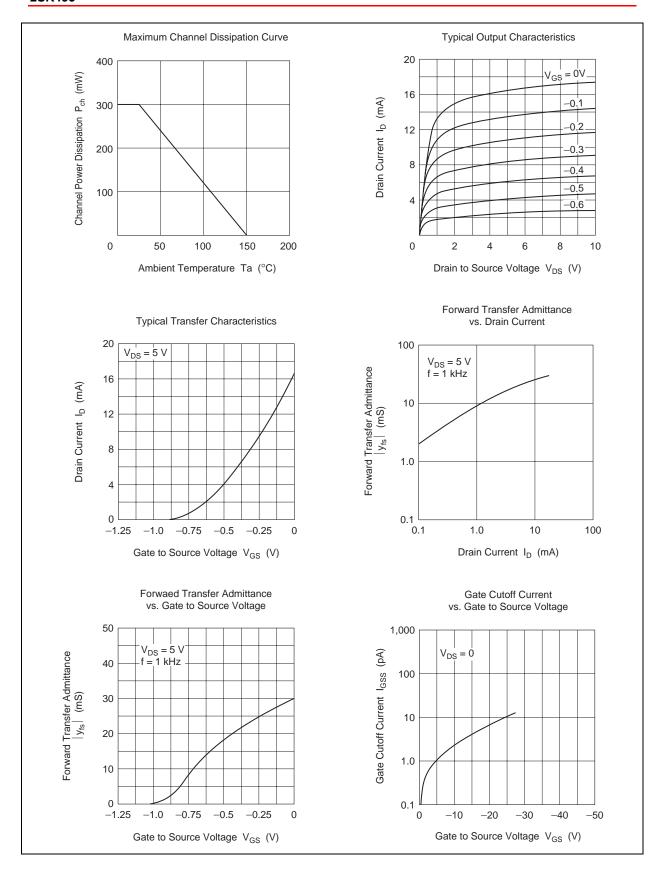
Electrical Characteristics

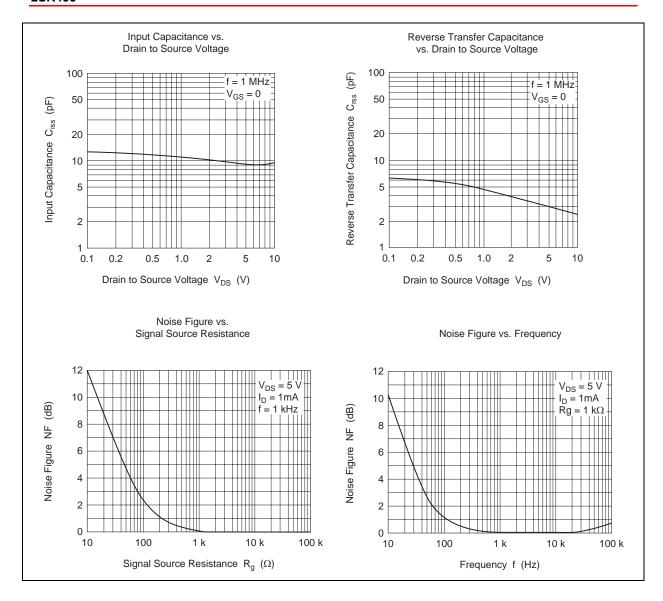
 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Gate to source breakdown voltage	V _{(BR)GSS}	-22	_	_	V	$I_G = -10 \mu A, V_{DS} = 0$
Gate cutoff current	I _{GSS}	_	_	-10	nA	$V_{GS} = -15 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	_	_	-2.5	V	$V_{DS} = 5 \text{ V}, I_{D} = 10 \mu\text{A}$
Drain current	I _{DSS} *1	12	_	30	mA	V_{DS} = 5 V, V_{GS} = 0, Pulse test
Forward transfer admittance	y _{fs}	20	_	_	mS	$V_{DS} = 5 \text{ V}, I_{D} = 10 \text{ mA},$ f = 1kHz
Input capacitance	Ciss	_	9.0	11.0	pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0,$ f = 1MHz
Reverse transfer capacitance	Crss	_	2.8	4.0	pF	$V_{DS} = 5 \text{ V}, V_{GS} = 0,$ f = 1MHz
Noise figure	NF	_	0.5	3.0	dB	$V_{DS} = 5 \text{ V}, I_D = 1 \text{ mA},$ $f = 1 \text{kHz}, \text{Rg} = 1 \text{k}\Omega$

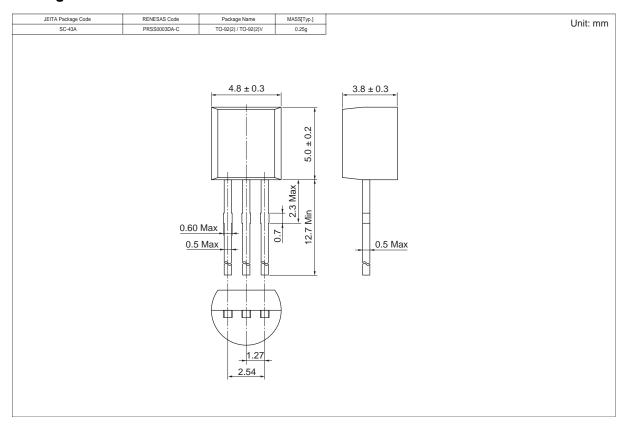
Note: 1. The 2SK435 is grouped by I_{DSS} as follows.

Grade	С	D	
I _{DSS}	12 to 22	18 to 30	





Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK435CTZ	2500	Radial taping, Hold box
2SK435DTZ	2500	Radial taping, Hold box

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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